

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETE	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage	V _{DS}	60	- v		
Gate-Source Voltage		V _{GS}			±20
Orantiana Drain Orana (Note 3)	Tc=25°C	168			
Continuous Drain Current ^(Note 3)	$T_{\rm C}=100^{\circ}{\rm C}$	l _D	119	А	
Pulsed Drain Current ^(Note 1)	Tc=25°C	I _{DM}	630		
Power Dissipation	Tc=25°C	D-	188	w	
	$T_{C}=100^{\circ}C$	Po	94		
Continuous Drain Current ^(Note 4)	T _A =25°C	1_	21	Α	
	T _A =70 [°] C	I _D	18	А	
Power Dissipation	T _A =25°C	Pp	3	W	
	T _A =70 [°] C	PD	2.1		
Single Pulse Avalanche Current ^{(Not}	las	54	А		
Single Pulse Avalanche Energy ^{(Note}	Eas	162	mJ		
Operating Junction and Storage Te	TJ,TSTG	-55~175	°C		
Thermal Resistance ^(Note 4)	Junction to Case	R _{θJC}	0.8	°C/W	
	Junction to Ambient	R _{0JA}	50		



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Electrical Characteristics (TA=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static		·					
Drain-Source Breakdown Voltage	BV _{DSS}	Vgs=0V, Id=250uA	60	-	-	V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	1.5	2.1	3		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A	-	2.6	3.3		
Drain-Source On-State Resistance		V _{GS} =4.5V, I _D =20A	- 3.9 5		5	mΩ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V	-	-	1	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA	
Dynamic ^(Note 6)							
Total Gate Charge	Qg		-	82	107	nC	
Gate-Source Charge	Qgs	$V_{DS}=30V, I_{D}=20A,$	-	14	-		
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	19	-		
Input Capacitance	Ciss		-	4728	6146	pF	
Output Capacitance	Coss	V _{DS} =30V, V _{GS} =0V, f=1MHz	-	1508	1960		
Reverse Transfer Capacitance	Crss		-	72	-		
Gate resistance	Rg	f=1MHz	-	1.3	-	Ω	
Turn-On Delay Time	td _(on)		-	13	-	ns	
Turn-On Rise Time	tr	V _{DS} =30V, I _D =20A,	-	26	-		
Turn-Off Delay Time	td _(off)	$V_{GS}=10V, R_G=3\Omega$	-	66	-		
Turn-Off Fall Time	tf		-	37	-		
Drain-Source Diode							
Diode Forward Current	I _S	Tc=25°C	-	-	168	A	
Pulsed Diode Forward Current	I _{SM}	1c=25 C	-	-	630		
Diode Forward Voltage	V _{SD}	I _S =20A, V _{GS} =0V	-	0.8	1.3	V	
Reverse Recovery Time	Trr	V _{DD} =30V,V _{GS} =0V	-	65	-	ns	
Reverse Recovery Charge	Qrr	Is=20A,dIs/dt=100A/us	-	73	-	nC	

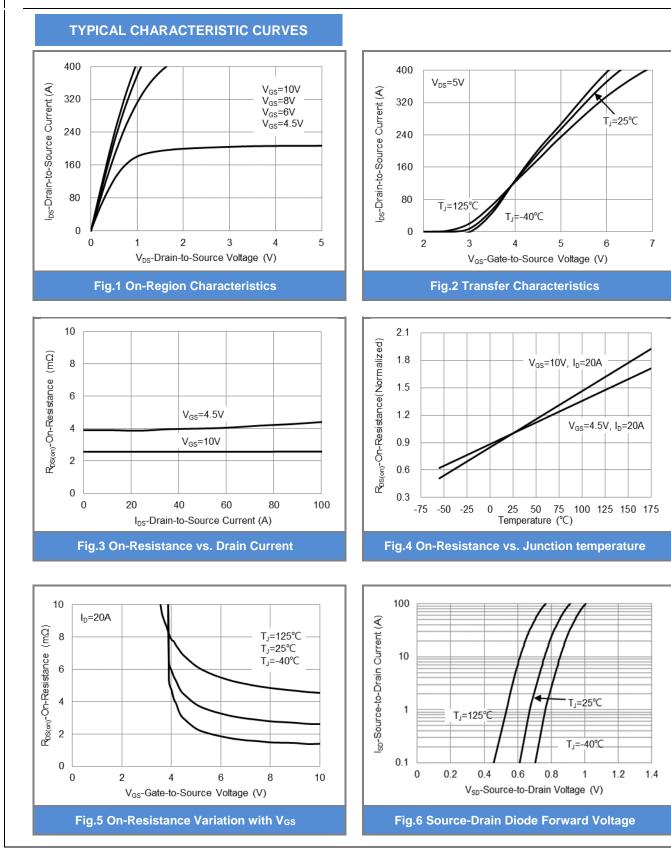
NOTES :

- 1. Pulse width100us, Duty cycle<2%.</td>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an $R_{\theta JC}=0.8^{\circ}C/W$, Package limited 100A.
- 4. $R_{\theta,JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. E_{AS} is calculated based on the condition of L=1mH, I_{AS}=18A, V_{DD}=30V, V_{GS}=10V. 100% test at L=0.1mH, I_{AS}=54A in production.
- 6. Guaranteed by design, not subject to production testing.

SEMI CONDUCTOR

PANJ

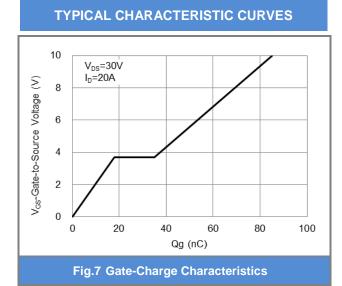
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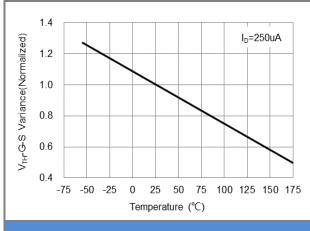


SEM CONDUCTOR

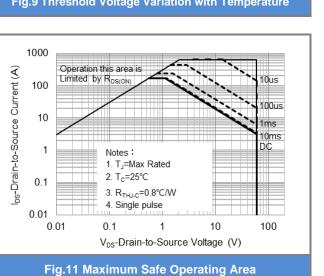
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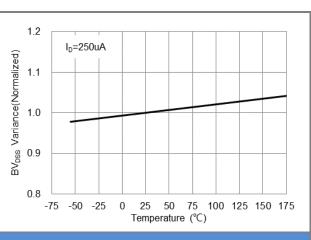
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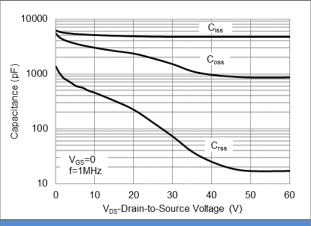




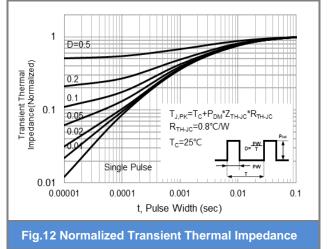












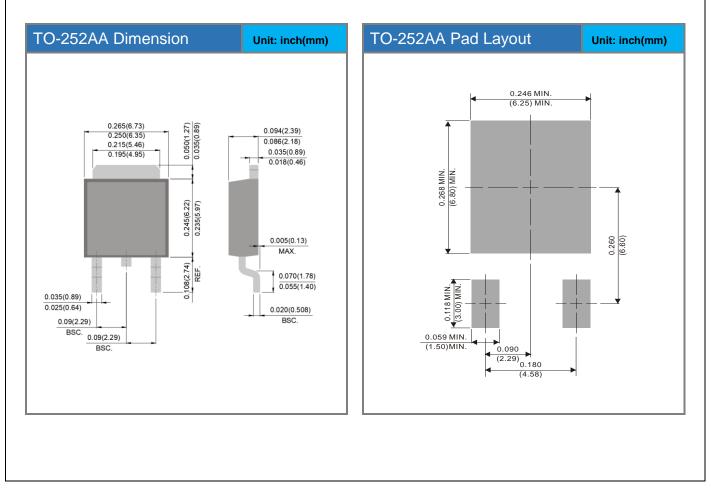


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Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJD100N06SA-AU	TO-252AA	3K pcs / 13" reel	100N06SA	

Packaging Information & Mounting Pad Layout





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